## EW-462, EW-562

**UNIPOLAR HALL EFFECT SWITCHES** 

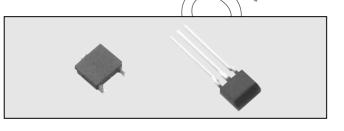
Note : It is requested to read and accept "IMPORTANT NOTICE" written on the back of the front cover of this catalogue

#### **ASAHI HALL EFFECT ICs**

ASAHI KASEI ELECTRONICS Hall Effect ICs are composed of a Ultla-high sensitive InSb Hall element and a signal processing IC chip in a package. ASAHI KASEI ELECTRONICS Hall Effect ICs have high sensitivity and good stability.

#### **FEATURES**

Bop(max):6mT High Sensitivity 4.5V to 18V Operation Highly Resistant to Mechanical Stress Stable Operation in Broad Temperature Range Compact Size With Load Resistance



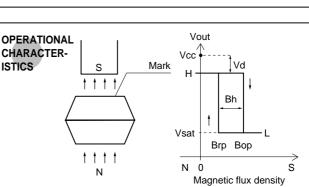
#### **APPLICATIONS**

Rotor Position Sensor for Precision Motors. Stroke Sensor Proximity Switch Encorder Current Switch etc.

# FUNCTIONAL BLOCK DIAGRAM

#### ABSOLUTE MAXIMUM RATINGS(Ta = 25 )

Item	Symbol	Limit	Unit
Supply Voltage * 1	Vcc	18	VY _
Output "ON" Current	I sink	15	mA
Operating Temperature Range	Topr	- 30~ + 115	$\Box$
Storage Temperature Range	Tstg	- 40~ + 125	Ť
Range * 1:Please refer to(Fig 1	0		>



### ELECTRICAL CHARACTERISTICS (Ta = 25 , Vcc = 4.5 ~ 18V DC.)

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit
Operate Point	Bop	Vcc=12V			6	mT
Release Point	Brp	Vcc=12V	0.5			mT
Hysteresis	Bh		0.2			mT
Output Saturation Voltage	Vsat	Output"L", Vcc=12V			0.4	V
Supply Current	I cc	Output"H", Vcc=12V			8	mA
Internal Load Resistance	R∟		7		13	к
Output Down Voltage	Vd				20	mV

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